

**Supercritical Carbon Dioxide**  
**Compatible Additives:**  
**Design, Synthesis, and Application of an**  
**Environmentally Friendly Development Process to**  
**Next Generation Lithography**  
*(Task Number: 425.031)*

**PIs:**

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**Graduate Students:**

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**Undergraduate Students:**

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*SRC/SEMATECH Engineering Research Center for Environmentally Benign Semiconductor Manufacturing*

# Objectives

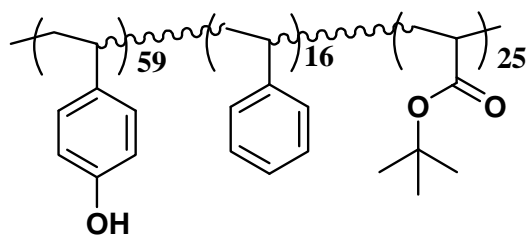
- **Develop chemistry platform for use of scCO<sub>2</sub> as a solvent with traditional photoresists**
  - **Design fluorinated quaternary ammonium salts (QAS) as CO<sub>2</sub> compatible additives**
  - **Elucidate underlying mechanisms of dissolution enhancement**
  - **Apply mechanistic understanding to creation on non-fluorinated additives**
- **Extend scCO<sub>2</sub> methods to molecular glass photoresists**

# ESH Metrics and Impact

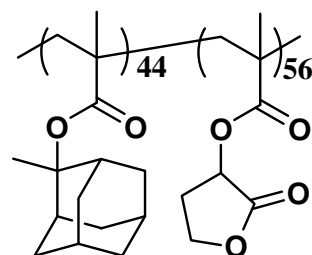
	Usage Reduction			Emmision Reduction			
Goals/Possibilities	Energy	Water	Chemicals	PFCs	VOCs	HAPs	Other
Reduce organic solvents used in processing materials	No energy used to purify and treat water	Eliminate need for water usage	Up to 100% reduction of organic solvents used	N/A	Minimal use of organic solvents	Up to 100% reduction of HAPs	N/A
Reduce processing time / temperature	Reduce anneal process costs	N/A	N/A	N/A	N/A	N/A	N/A
Additive processing	N/A	N/A	Eliminate waste of costly material	N/A	Minimal use of organic solvents	N/A	N/A

# Systems of Interest

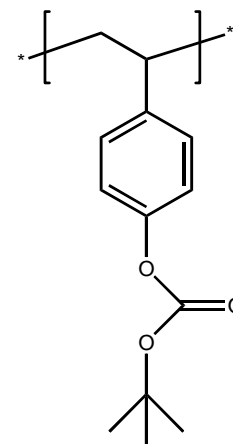
- **Model photoresists in their protected forms**



ESCAP



193nm-resist

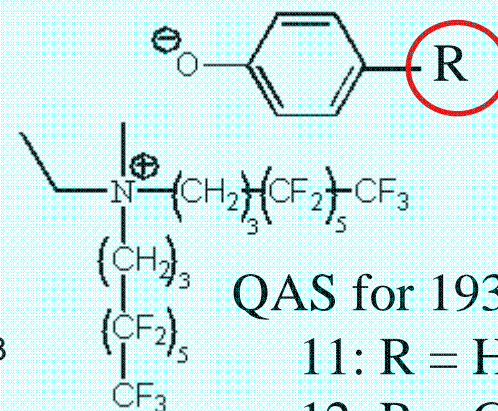
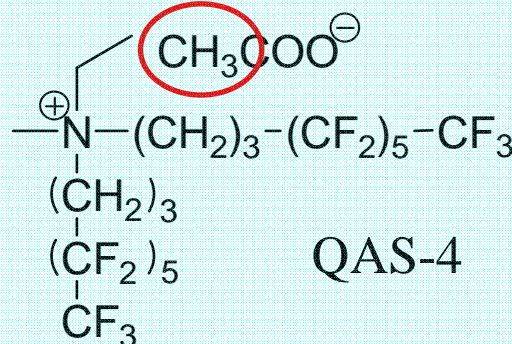
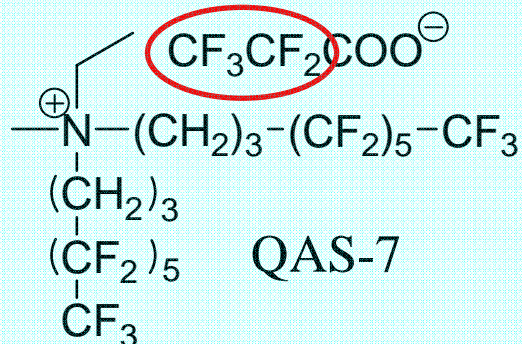


PHOST

- **QAS Additives**

- **Previously shown to be soluble in CO<sub>2</sub>**

QAS for ESCAP & PHOST



QAS for 193nm-resist

11: R = H

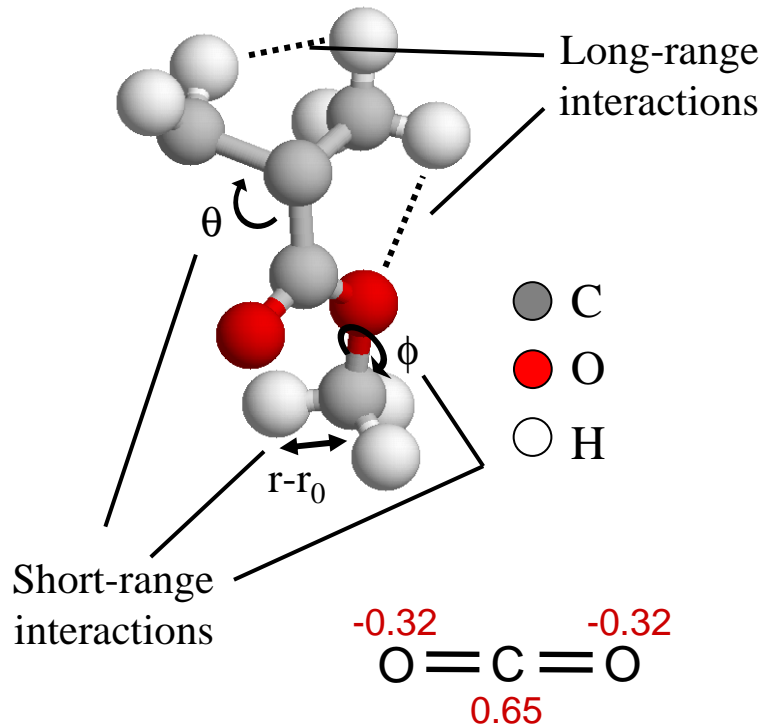
12: R = CH<sub>3</sub>

13: R = CF<sub>3</sub>

14: R = NO<sub>2</sub>

# Model

- Simulation allows screening of large numbers of systems and enables direct observation of molecular behavior



charges important: scCO<sub>2</sub> has a large quadrupole moment

OPLS Model:

$$V_{\text{tot}} = \underbrace{V_{\text{LJ}} + V_{\text{coul}}}_{\text{Intermolecular}} + \underbrace{V_{\text{bon}} + V_{\text{ang}} + V_{\text{tors}}}_{\text{Intramolecular}}$$

$$V_{\text{LJ}} = 4 \cdot \epsilon \cdot \left[ \left( \frac{\sigma}{r} \right)^{12} - \left( \frac{\sigma}{r} \right)^6 \right]$$

$$V_{\text{coul}} = \frac{q_i \cdot q_j}{4 \cdot \epsilon_0 \cdot \epsilon \cdot r}$$

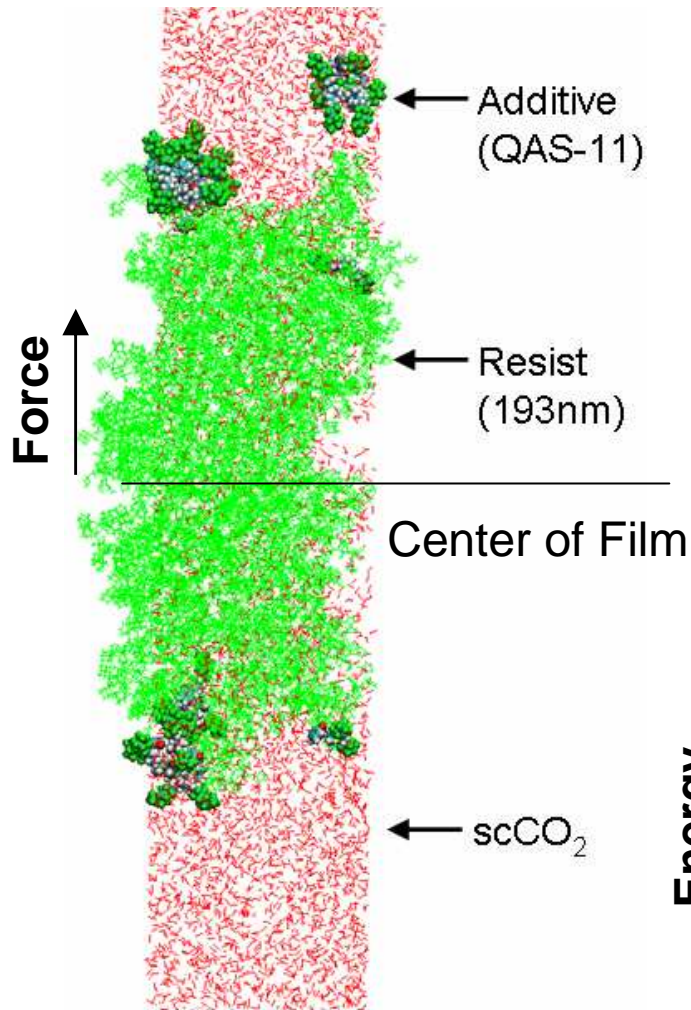
$$V_{\text{bon}} = \frac{1}{2} \cdot k_{\text{bon}} \cdot (r - r_0)^2$$

$$V_{\text{ang}} = \frac{1}{2} \cdot k_{\text{ang}} \cdot (\theta - \theta_0)^2$$

$$V_{\text{tors}} = \sum_n k_n \cdot (1 + \cos(n \cdot \phi - \phi_0))$$

- OPLS force field employed for most parameters
- We calculated charges ( $q_i$ ) using quantum mechanics
- Process Conditions:  $T = 340\text{K}$  ( $\sim 67^\circ\text{C}$ )  
 $P = 345$  bar

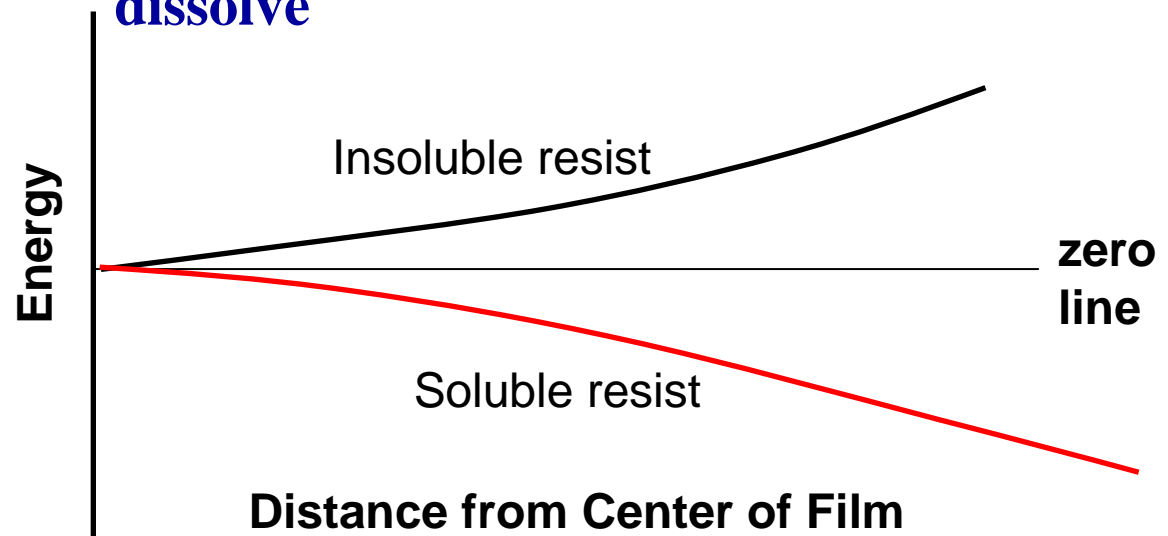
# Free Energy Calculation



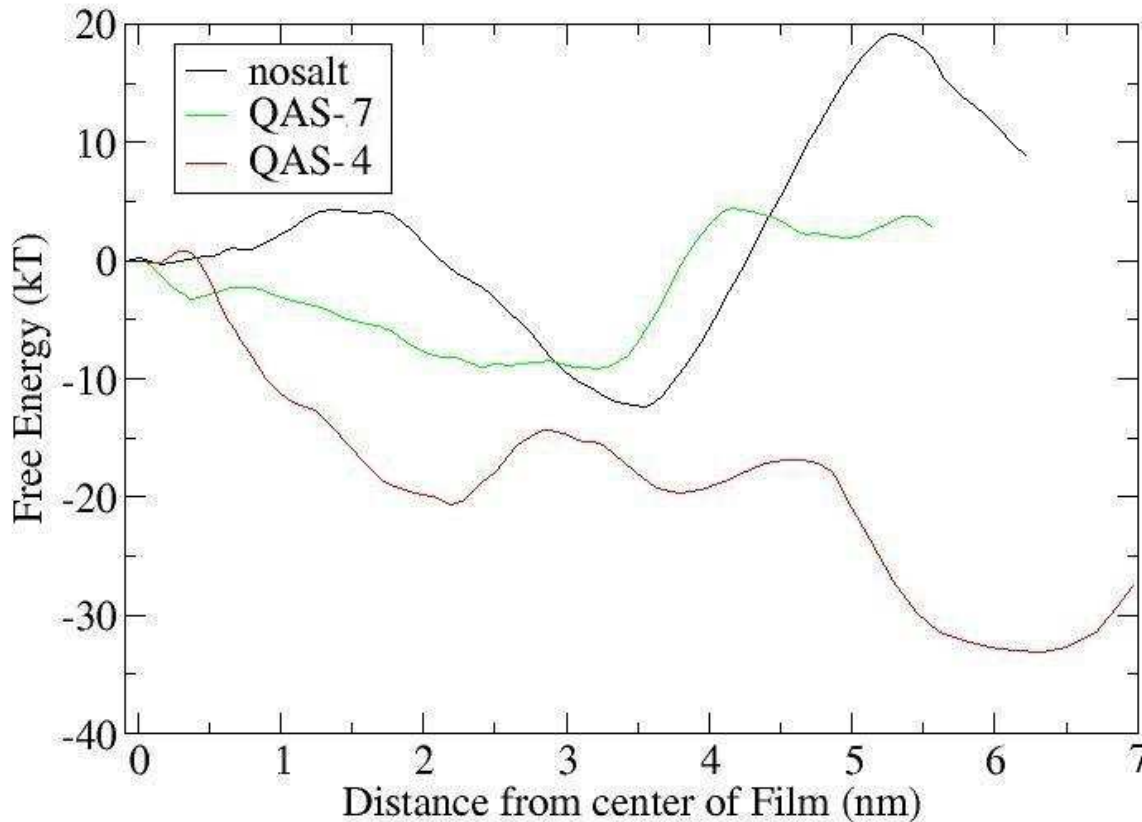
- Thin films of resist are equilibrated in scCO<sub>2</sub> via MD simulation
- Integrating the force on each chain as a function of position provides free energy

$$F(z) = \int_z^{z_\infty} \langle f(z') \rangle dz' + F(z_o)$$

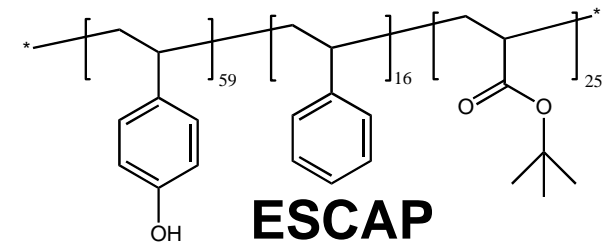
- If the energy is lower at the surface than the center, the film is unstable and will dissolve



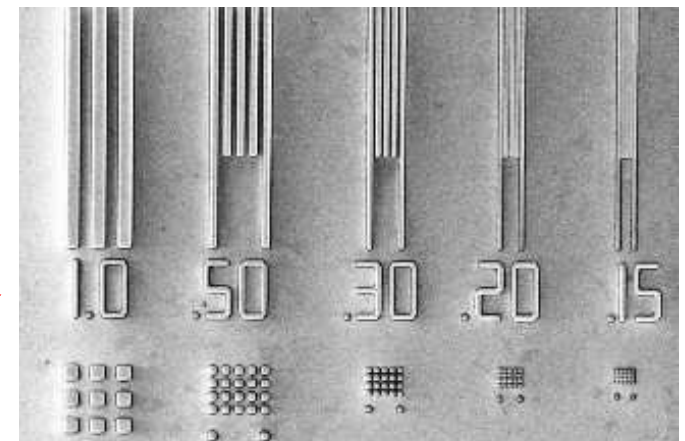
# Sample Result: ESCAP Energy Curve



Experimental Results:  
No salt – 0 nm/sec  
QAS-7 – 0 nm/sec  
QAS-4 – 20 nm/sec

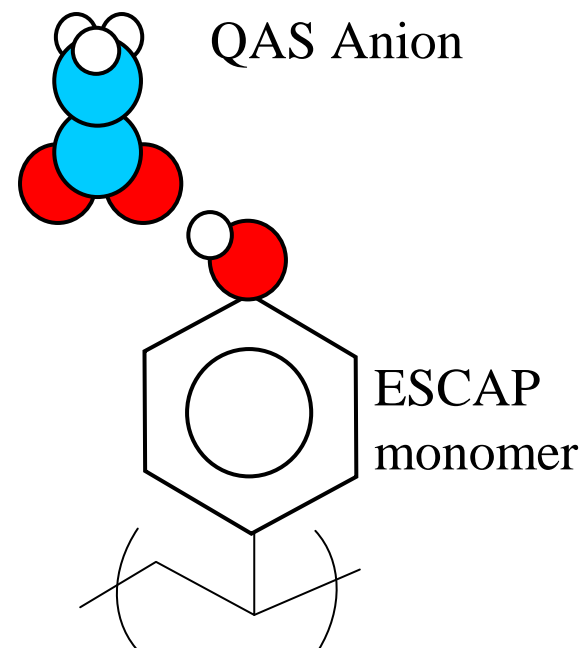
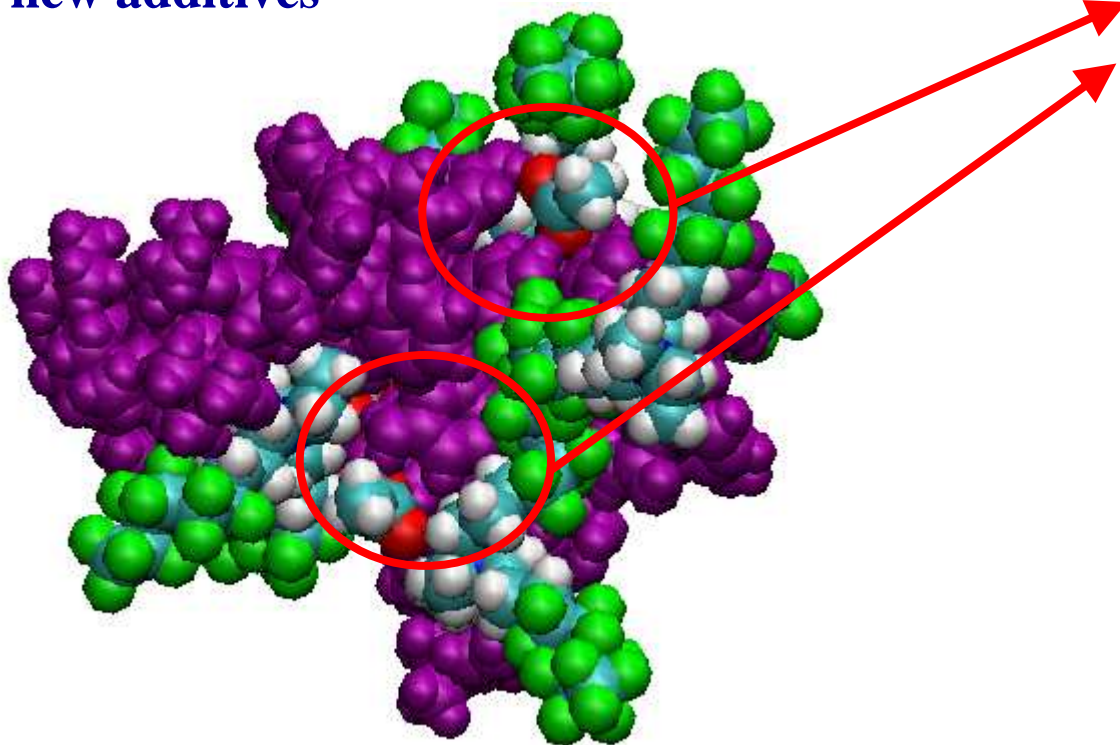


- Only addition of QAS4 to ESCAP results in reduced energy at surface of film (right of plot), indicating eventual dissolution
- Viability confirmed experimentally



# ESCAP Mechanism with QAS4

- The  $\text{-OH}$  group of ESCAP associates with the anions; contacts last  $>500$  ps.
- Reducing available polar regions increases solubility in  $\text{scCO}_2$
- Will use understanding of mechanism to develop new additives

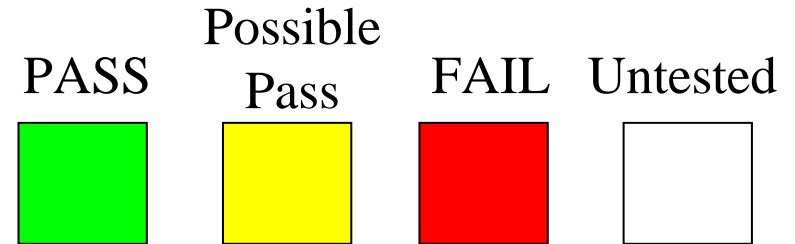


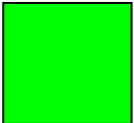
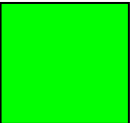














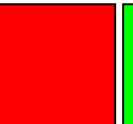

















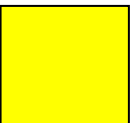




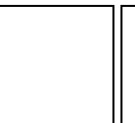
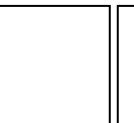
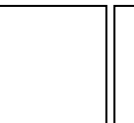

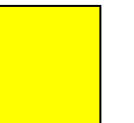
- $\text{scCO}_2$  not shown for clarity
- **Purple** – ESCAP
- **Green** – Fluorine (QAS-4)
- **Cyan** – Carbon (QAS-4)
- **Red** – Oxygen (QAS-4)
- **White** – Hydrogen (QAS-4)



# Summary of Fluorinated Additive Results

- We have applied these methods to a range of additive-resist combinations to screen for promising systems
- Excellent agreement with experiment

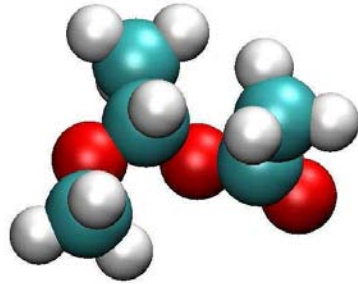


Photoresist	Additive										
	QAS4	QAS6	QAS7	QAS11	QAS12	QAS13	QAS14	Isocyanate	TMDS	HMDS	none
ESCAP											
193nm											
PHOST											
Molecular Glass I											

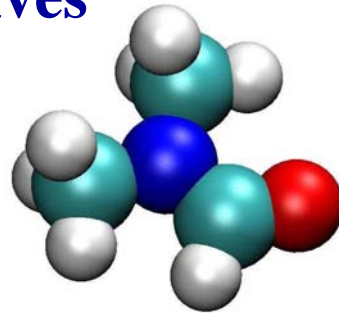
Reactive Additives Not Discussed Today

# Non-Fluorinated Systems

- Potential Additives

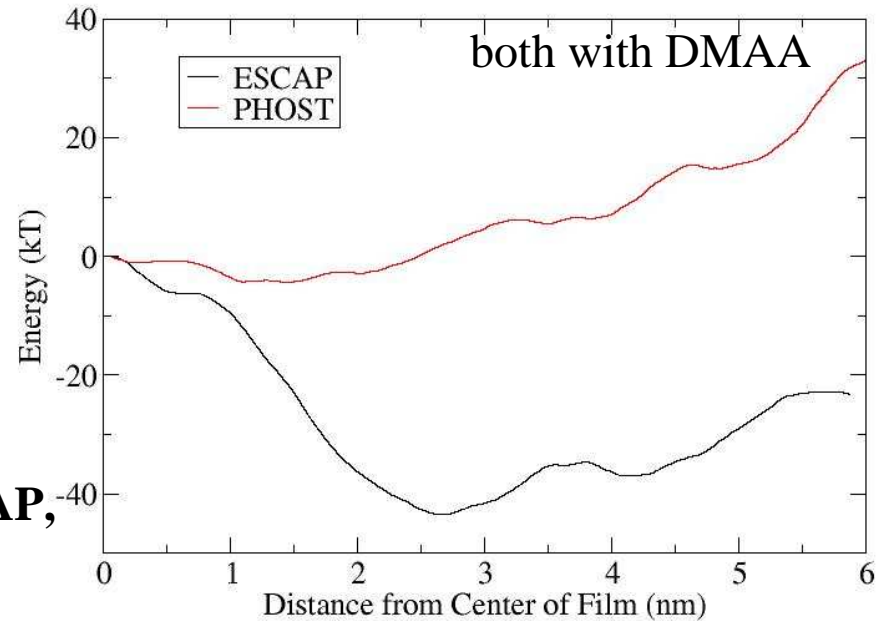


PGMEA

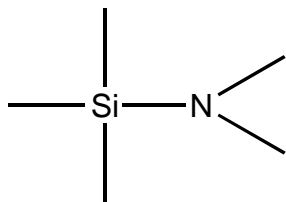


DMAA

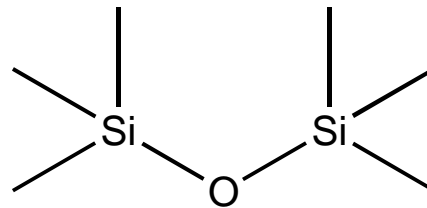
Effective with ESCAP,  
but not PHOST



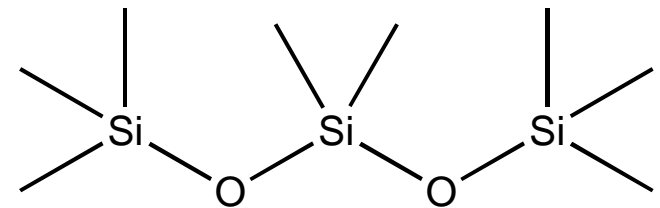
- Alternative solvents not needing fluorinated additives



DMTsilane



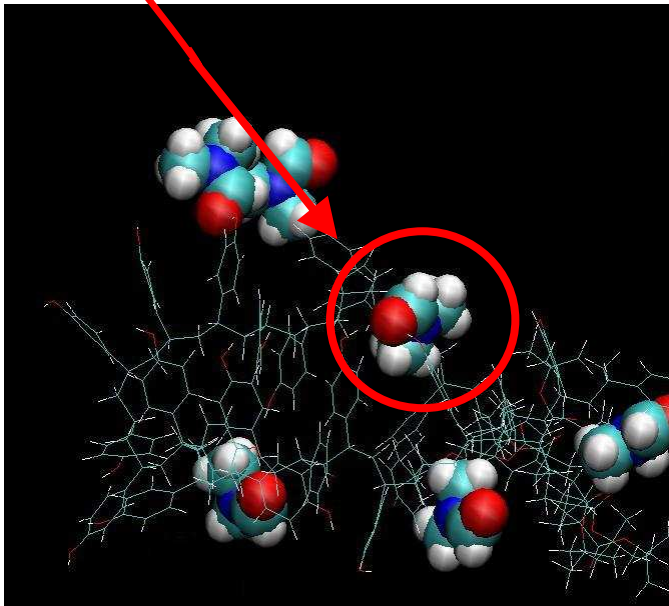
HMDsilane



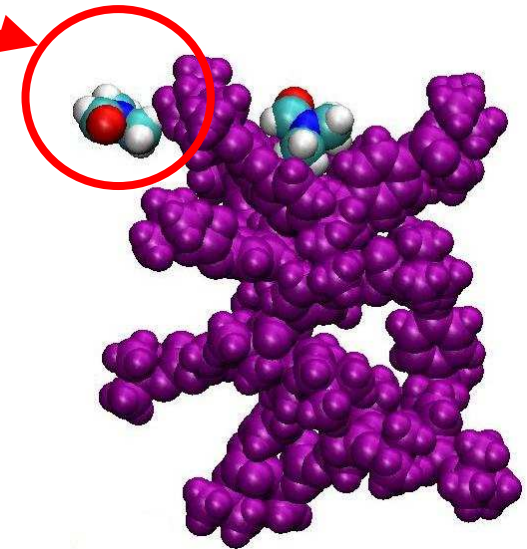
OMTsilane

# DMAA Mechanism

- Additive was based on applying our understanding of QAS4 effectiveness on ESCAP
- DMAA demonstrates similar hydrogen bonding
- Ineffective with PHOST; obstructs terminal t-butyl group, instead exposing polar region, reducing scCO<sub>2</sub> solubility

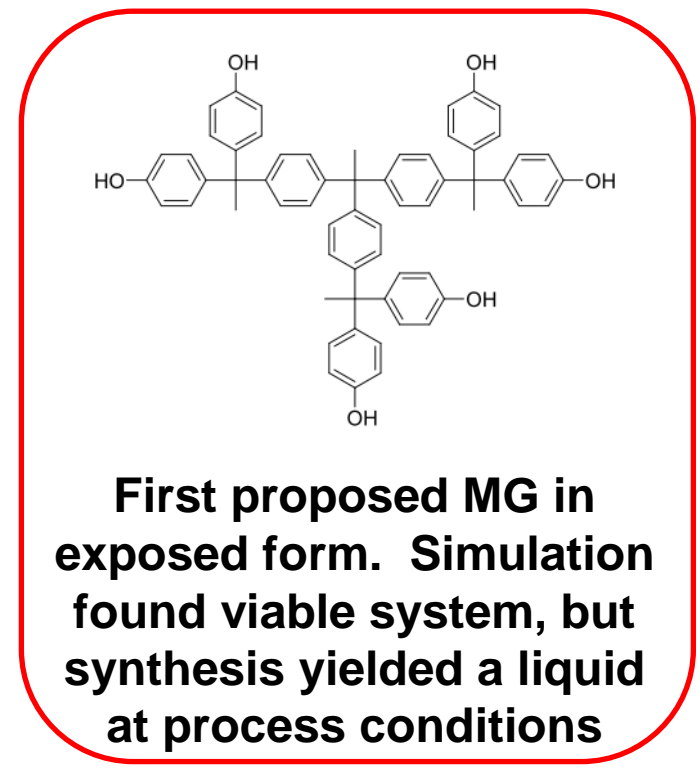
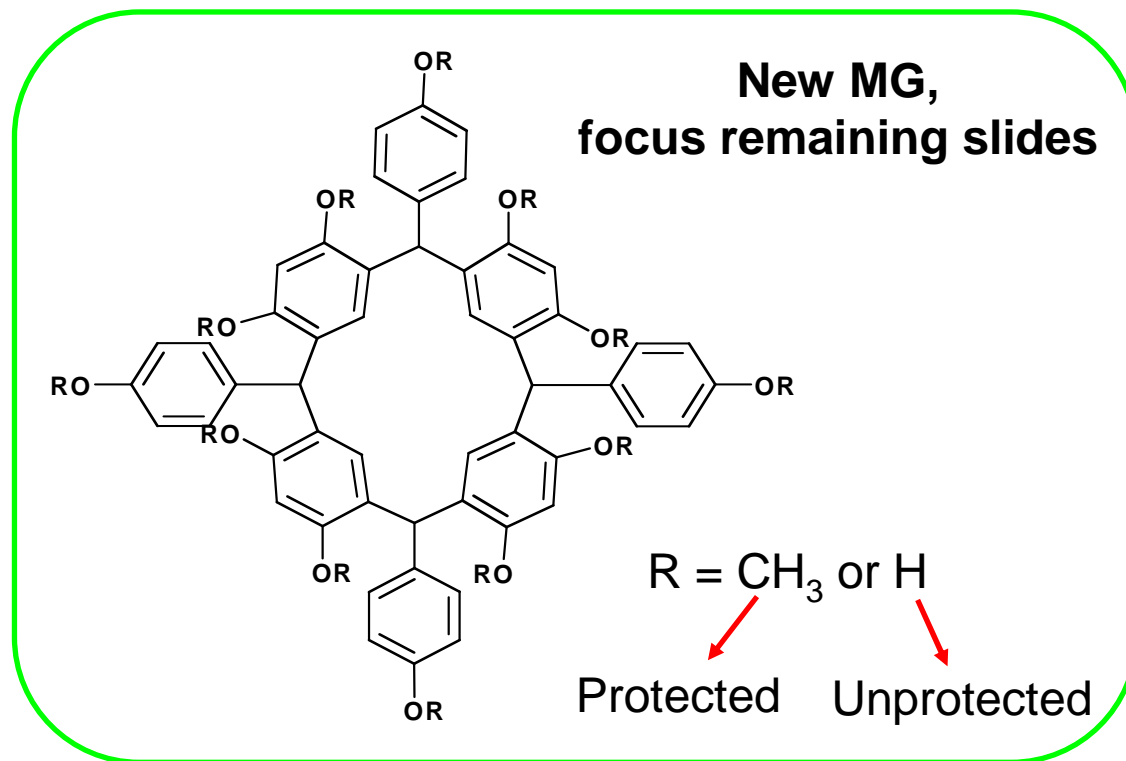


Can develop non-fluorinated additives, but they are more resist-specific



# Molecular Glass (MG) Resists

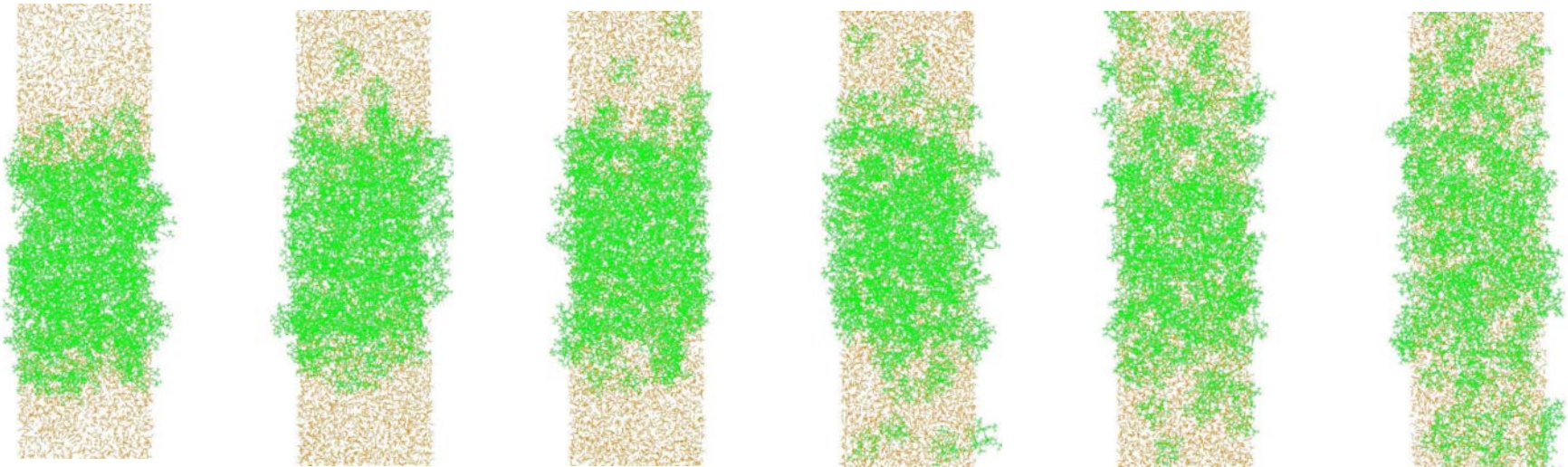
- Molecular Glass have low LER due to small size
- Experimental synthesis and testing is expensive and does not guarantee results; screening via simulation saves resources



# Molecular Glass in scCO<sub>2</sub>

- Protected MG dissolved in scCO<sub>2</sub> without additive; unprotected form insoluble
- No testing with additives necessary, system shows most robust dissolution to date; no free-energy curve needed
- Highly promising results to be confirmed experimentally

Time (1-2ns between images)



*SRC/SEMATECH Engineering Research Center for Environmentally Benign Semiconductor Manufacturing*

# Industrial Interactions and Technology Transfer

- **Regular discussions with Intel via Richard Schenker**
- **Interactions with Dario Goldfarb from IBM**
- **Interactions with Kenji Yoshimoto from Global Foundry**



# Future Plans

## Next Year Plans

- Complete characterization of bulk properties of new potential molecular glass resists and silicone-based solvents
- Verification of new materials via laboratory experiments
- Additional screening of new non-fluorinated additives for use with traditional photoresists

## Long-Term Plans

- To expand use of additives for scCO<sub>2</sub> and environmentally friendly silicone fluids for development of positive tone resists
- To create new chemistries for patterning and functionalizing small, non-polar molecules in scCO<sub>2</sub>

# Publications, Presentations, and Recognitions/Awards

## **Publications**

- **Tanaka M, Rastogi A, Toepperwein GN, Riggleman RA, Felix N, de Pablo JJ, Ober CK. “Fluorinated Quaternary Ammonium Salts as Dissolution Aids for Polar Polymers in Environmentally Benign Supercritical Carbon Dioxide”, Chemistry of Materials (2009), 21(14), 3121-3135**
- **Rastogi A, Toepperwein GN, Tanaka M, Riggleman RA, de Pablo JJ, Ober CK. “Contact Analysis Studies of an ESCAP resist with scCO<sub>2</sub> compatible additives”, Proc. SPIE (2009)**
- **Sha J, Ober CK, “Fluorine- and Siloxane-Containing Polymers for Supercritical Carbon Dioxide Lithography”, Polymer International (2009), 58(3), 302-306**

## **Presentations**

- **ERC Telesminar (Oct 2008). “Environmentally Benign Development of Standard Resists in Supercritical Carbon Dioxide Using CO<sub>2</sub> Compatible Salts”**